## PNP -500mA -12V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value
V <sub>CC</sub>	-12V
I <sub>C(MAX.)</sub>	-500mA
R <sub>1</sub>	$4.7$ k $\Omega$
$R_2$	47kΩ

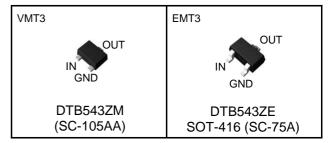
# Features

- 1) Built-In Biasing Resistors
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types :DTD543Z series
- 6) Lead Free/RoHS Compliant.

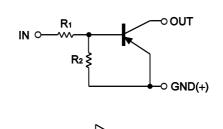
#### Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

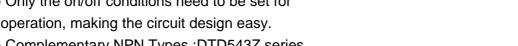
#### Outline



#### •Inner circuit



GND(+)



#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTB543ZM	VMT3	1212	T2L	180	8	8,000	Y13
DTB543ZE	EMT3	1616	TL	180	8	3,000	Y13

## ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Supply voltage	V <sub>cc</sub>	-12	V
Input voltage	V <sub>IN</sub>	−12 to +5	V
Collector current	I <sub>C(MAX.)</sub> *1	-500	mA
Power dissipation	$P_{D}^{*2}$	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

## ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100 \mu A$	-	-	-0.3	V
Input voltage	$V_{I(on)}$	$V_0 = -0.3V, I_0 = -20mA$	-2.5	-	1	V
Output voltage	$V_{O(on)}$	$I_0 / I_1 = -100 \text{mA} / -5 \text{mA}$	-	-0.06	-0.3	V
Input current	I <sub>I</sub>	$V_1 = -5V$	-	-	-1.4	mA
Output current	I <sub>O(off)</sub>	$V_{CC} = -12V, V_I = 0V$	-	-	-0.5	μΑ
DC current gain	G <sub>I</sub>	$V_{O} = -2V, I_{O} = -100 \text{mA}$	140	-	ı	-
Input resistance	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	-	8	10	12	-
Transition frequency	f <sub>T</sub> *1	$V_{CE} = -10V, I_{E} = 5mA$ f = 100MHz	-	260	-	MHz

<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

#### ●Electrical characteristic curves(Ta = 25°C)

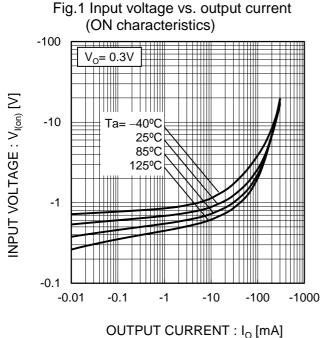
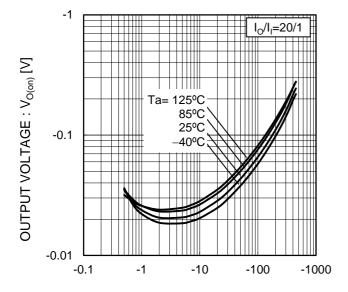


Fig.2 Output current vs. input voltage (OFF characteristics) -100  $V_{CC} = 5V$ OUTPUT CURRENT : Io [mA] -10 -1 Ta= 125°C 85°C -0.1 25°C ≡ -40°C -0.01 0 -0.5 -1 -1.5 -2 INPUT VOLTAGE :  $V_{I(off)}[V]$ 

Fig.4 DC current gain vs. output current Fig.3 Output current vs. output voltage -200 1000 1.0mA Ta= 25°C  $V_0 = 5V$ -180 -0.9mA -0.8mA -160 OUTPUT CURRENT : Io [mA] -0.7mA -140 -0.6mA 100 -120 -0.5mA -100 -0.4mA L -0.3mA L -0.2mA Ta= 125°C 85°C -80 25°C 10 40°C -60 -40 -0.1mA -20 0mA 0 0 -0.2 -0.4 -0.6 -0.8 -1 -0.01 -0.1 -10 -100 -1000 OUTPUT VOLTAGE: Vo [V] OUTPUT CURRENT : Io [mA]

## ●Electrical characteristic curves(Ta = 25°C)

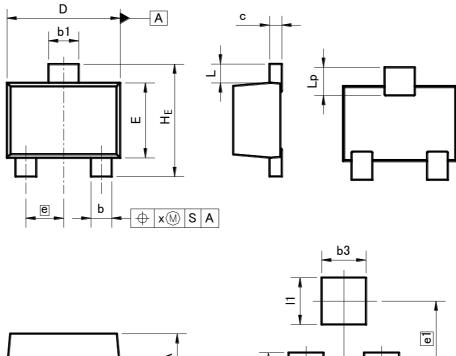
Fig.5 Output voltage vs. output current

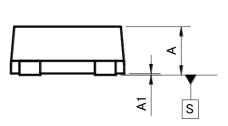


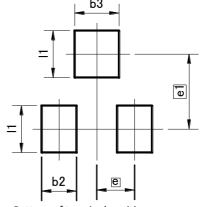
OUTPUT CURRENT :  $I_O$  [mA]

## ●Dimensions (Unit:mm)

## VMT3







Pattern of terminal position areas [Not a recommended pattern of soldering pads]

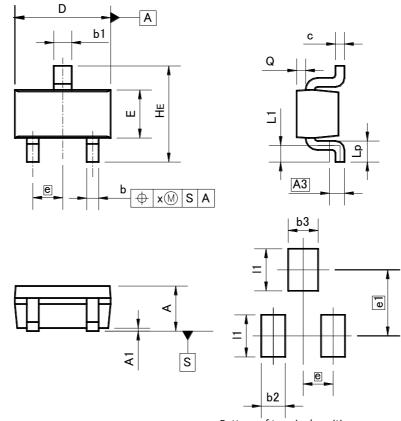
DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0.000	0.004	
b	0.17	0.27	0.007	0.011	
b1	0.27	0.37	0.011	0.015	
С	0.08	0.18	0.003	0.007	
D	1.10	1.30	0.043	0.051	
Е	0.70	0.90	0.028	0.035	
е	0.4	40	0.0	02	
HE	1.10	1.30	0.043	0.051	
L	0.10	0.30	0.004	0.012	
Lp	0.20	0.40	0.008	0.016	
х	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b2	ı	0.37	_	0.015
b3	_	0.47	_	0.019
e1	0.80		0.0	31
l1	-	0.50	_	0.020

Dimension in mm / inches

## ●Dimensions (Unit : mm)

## EMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX		
Α	0.60	0.80	0.024	0.031		
A1	0.00	0.10	0.000	0.004		
A3	0.3	25	0.0	10		
b	0.15	0.30	0.006	0.012		
b1	0.25	0.40	0.010	0.016		
С	0.10	0.20	0.004	0.008		
D	1.50	1.70	0.059	0.067		
Е	0.70	0.90	0.028	0.035		
е	0.	50 0.020		20		
HE	1.40	1.80	0.055	0.071		
L1	0.10	_	0.004	_		
Lp	0.15	_	0.006	_		
Q	0.05	0.25	0.002	0.010		
х		0.10		0.004		

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
b2	_	0.40	ı	0.016	
b3	_	0.50	_	0.020	
e1	1.10		0.0	43	
l1	_	0.70	ı	0.028	

Dimension in mm / inches

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